SHARP PC8172xNSZ Series

## PC8172xNSZ Series

# Low Input Current Type Photocoupler

#### **■** Features

- 1. Low input current type. (I<sub>F</sub>=0.1mA)
- High resistance to noise due to high common rejection voltage. (CMR:MIN. 10kV/μs)
- 3. Compact dual-in line package.
- 4. Isolation voltage. (V<sub>iso (rms)</sub>:5kV)

#### ■ Applications

- 1. Programmable controllers.
- 2. Facsimiles.
- 3. Telephones.

| Absolute Maximum Ratings (T <sub>a</sub> =25°C) |                             |                        |             |      |  |  |  |  |  |
|---|-----------------------------|------------------------|-------------|------|--|--|--|--|--|
|   | Parameter                   | Symbol                 | Rating      | Unit |  |  |  |  |  |
| Input   | Forward current             | $I_F$                  | 10          | mA   |  |  |  |  |  |
|   | *1 Peak forward current     | $I_{FM}$               | 200         | mA   |  |  |  |  |  |
|   | Reverse voltage             | $V_R$                  | 6           | V    |  |  |  |  |  |
|   | Power dissipation           | P                      | 15          | mW   |  |  |  |  |  |
| Output  | Collector-emitter voltage   | $V_{CEO}$              | 70          | V    |  |  |  |  |  |
|   | Emitter-collector voltage   | $V_{ECO}$              | 6           | V    |  |  |  |  |  |
|   | Collector current           | $I_C$                  | 50          | mA   |  |  |  |  |  |
|   | Collector power dissipation | $P_{C}$                | 150         | mW   |  |  |  |  |  |
| Total   | power dissipation           | P <sub>tot</sub>       | 170         | mW   |  |  |  |  |  |
| Opera   | ting temperature            | $T_{opr}$              | -30 to +100 | °C   |  |  |  |  |  |
| Storag  | ge temperature              | $T_{stg}$              | -55 to +125 | °C   |  |  |  |  |  |
| *2 Isolat                                       | ion voltage                 | V <sub>iso (rms)</sub> | 5           | kV   |  |  |  |  |  |
| *3 Soldering temperature                        |                             | $T_{sol}$              | 260         | °C   |  |  |  |  |  |

<sup>\*1</sup> Pulse width≤100µs, Duty ratio=0.001

### ■ Outline Dimensions (Unit: mm) Anode mark 0.6<sup>±0.2</sup> †O+ 8 1 7 2 SHARP .54±0.25 $6.5^{\pm0.5}$ $7.62^{\pm0.3}$ $4.58^{\pm0.5}$ Epoxy resin $\underline{0.26}^{\pm0.1}$ $\theta$ : 0 to 13° Internal connection diagram 1 Anode 1

② Cathode③ Emitter④ Collector

<sup>\*2 40</sup> to 60%RH, AC for 1 minute, f=60Hz

<sup>\*3</sup> For 10s

| ■ Electro-optical Characteristics |                                      |           |                       |   |                    |                    |      | $(T_a=25^{\circ}C)$ |
|-----------------------------------|--------------------------------------|-----------|-----------------------|---|--------------------|--------------------|------|---------------------|
| Parameter                         |                                      | Symbol    | Conditions            | MIN.  | TYP.               | MAX.               | Unit |                     |
| Input                             | Forward voltage                      |           | $V_F$                 | I <sub>F</sub> =5mA   | _                  | 1.2                | 1.4  | V                   |
|                                   | Reverse current                      |           | $I_R$                 | V <sub>R</sub> =4V  | _                  | -                  | 10   | μΑ                  |
|                                   | Terminal capacitance                 |           | $C_t$                 | V=0, f=1kHz   | _                  | 30                 | 250  | pF                  |
| Ħ                                 | Collector dark current               |           | $I_{CEO}$             | $V_{CE} = 50V, I_{F} = 0$   | -                  | _                  | 100  | nA                  |
| Output                            | Collector-emitter breakdown voltage  |           | $BV_{CEO}$            | I <sub>C</sub> =0.1mA, I <sub>F</sub> =0  | 70                 | _                  | _    | V                   |
|                                   | Emitter-collector breakdown voltage  |           | $BV_{ECO}$            | $I_{E}=10\mu A, I_{F}=0$  | 6                  | _                  | _    | V                   |
| Transfer characteristics          | Collector current                    |           | $I_C$                 | I <sub>F</sub> =0.1mA, V <sub>CE</sub> =5V  | 0.1                | -                  | 0.5  | mA                  |
|                                   | Collector-emitter saturation voltage |           | V <sub>CE (sat)</sub> | I <sub>F</sub> =5mA, I <sub>C</sub> =1mA  | -                  | 0.1                | 0.3  | V                   |
|                                   | Isolation resistance                 |           | R <sub>ISO</sub>      | DC500V 40 to 60%RH  | 5×10 <sup>10</sup> | 1×10 <sup>11</sup> | _    | Ω                   |
|                                   | Floating capacitance                 |           | $C_{\rm f}$           | V=0, f=1MHz   | _                  | 0.6                | 1.0  | pF                  |
|                                   | Response time                        | Rise time | $t_r$                 | $V_{CE}$ =2V, $I_{C}$ =2mA, $R_{L}$ =100 $\Omega$   | _                  | 4                  | 18   | μs                  |
|                                   |                                      | Fall time | $t_{\rm f}$           |   | _                  | 3                  | 18   | μs                  |
|                                   | *4 Common mode rejection voltage CM  |           | CMR                   | T <sub>a</sub> =25°C, R <sub>L</sub> =470Ω, V <sub>CM</sub> =1.5kV (peak),<br>I <sub>F</sub> =0mA, V <sub>CC</sub> =9V, Vnp=100mV | 10                 | _                  | _    | kV/μs               |

<sup>\*4</sup> Refer to Fig.1.

Fig.1 Test Circuit for Common Mode Rejection Voltage

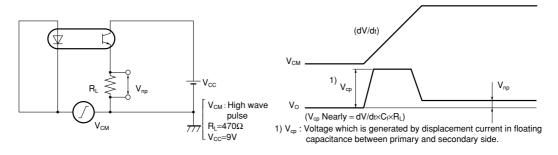


Fig.2 Forward Current vs. Ambient Temperature

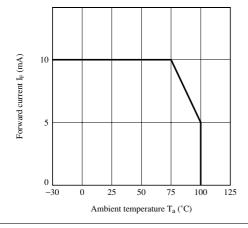
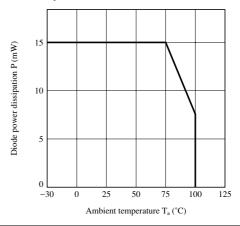


Fig.3 Diode Power Dissipation vs. Ambient Temperature



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Fig.4 Collector Power Dissipation vs. Ambient Temperature

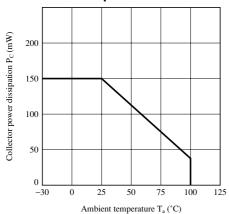


Fig.6 Peak Forward Current vs. Duty Ratio

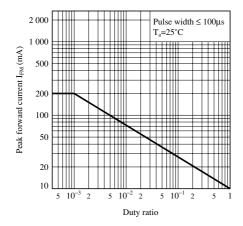
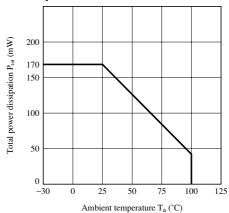


Fig.5 Total Power Dissipation vs. Ambient Temperature



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